

TOSHIBA Transistor Silicon NPN Epitaxial Type

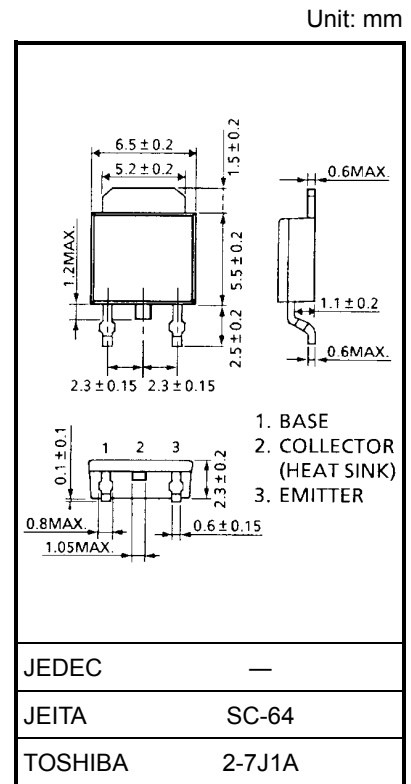
2SC5886

High-Speed Switching Applications
DC-DC Converter Applications

- High DC current gain: $h_{FE} = 400$ to 1000 ($I_C = 0.5$ A)
- Low collector-emitter saturation: $V_{CE(sat)} = 0.22$ V (max)
- High-speed switching: $t_f = 55$ ns (typ.)

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	100	V
Collector-emitter voltage		V_{CEX}	80	V
		V_{CEO}	50	
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC	I_C	5	A
	Pulse	I_{CP}	10	
Base current		I_B	0.5	A
Collector power dissipation	$T_a = 25^\circ\text{C}$	P_c	1	W
	$T_c = 25^\circ\text{C}$		20	
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$



Weight: 0.36 g (typ.)

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = 100$ V, $I_E = 0$	—	—	100	nA
Emitter cut-off current		I_{EBO}	$V_{EB} = 7$ V, $I_C = 0$	—	—	100	nA
Collector-emitter brakedown voltage		$V_{(BR)CEO}$	$I_C = 10$ mA, $I_B = 0$	50	—	—	V
DC current gain	$h_{FE(1)}$	h_{FE}	$V_{CE} = 2$ V, $I_C = 0.5$ A	400	—	1000	
	$h_{FE(2)}$		$V_{CE} = 2$ V, $I_C = 1.6$ A	200	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 1.6$ A, $I_B = 32$ mA	—	—	0.22	V
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = 1.6$ A, $I_B = 32$ mA	—	—	1.10	V
Switching time	Rise time	t_r	See Figure 1 circuit diagram $V_{CC} \approx 24$ V, $R_L = 15 \Omega$ $I_{B1} = 32$ mA, $I_{B2} = -53$ mA	—	63	—	ns
	Storage time	t_{stg}		—	560	—	
	Fall time	t_f		—	55	—	

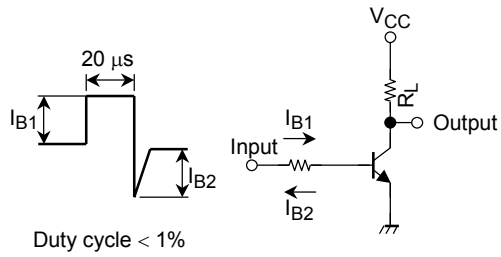
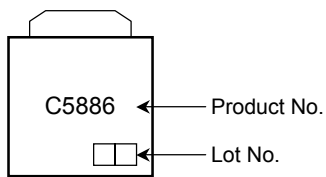
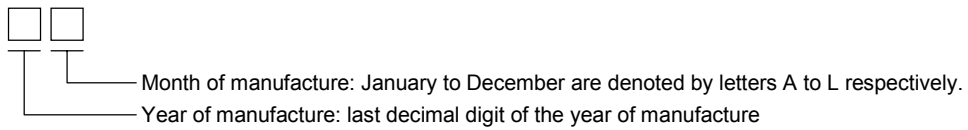


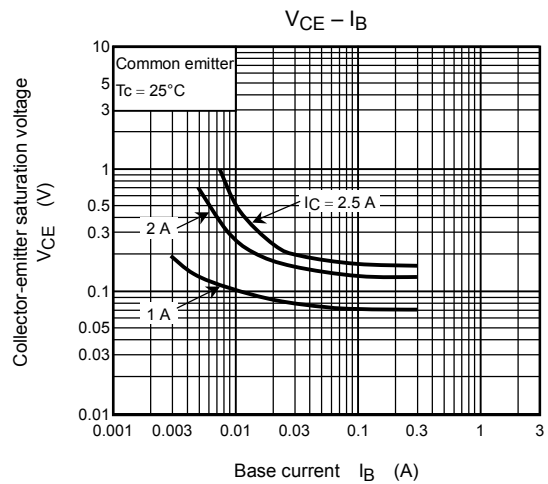
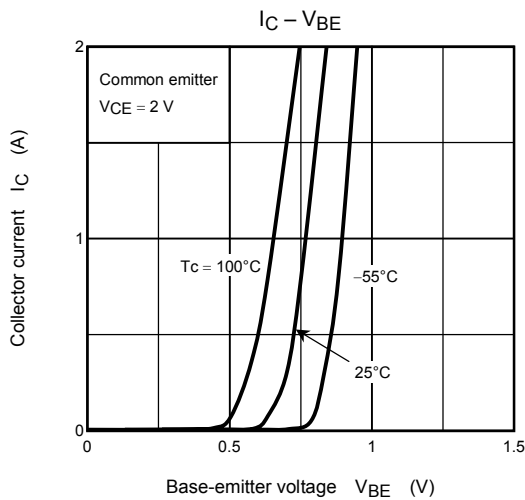
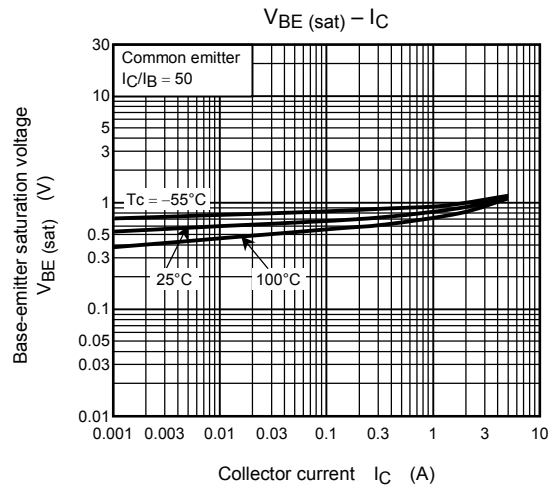
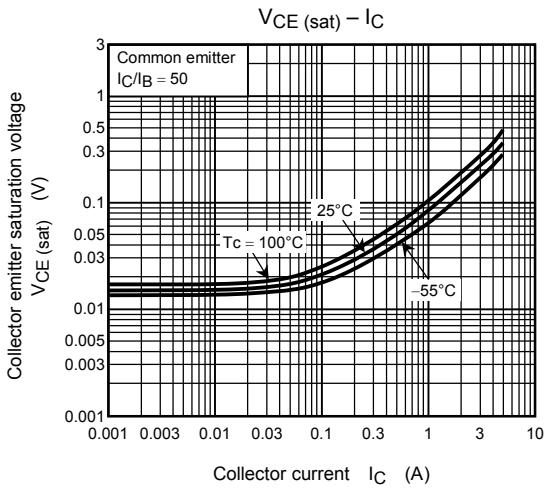
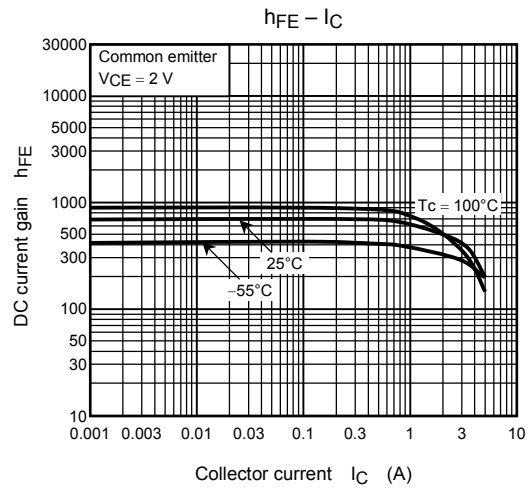
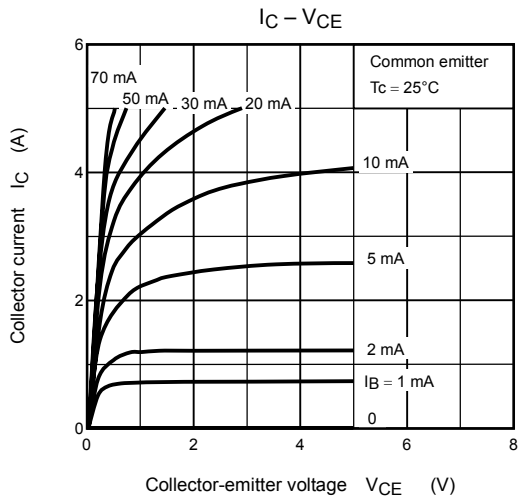
Figure 1 Switching Time Test Circuit & Timing Chart

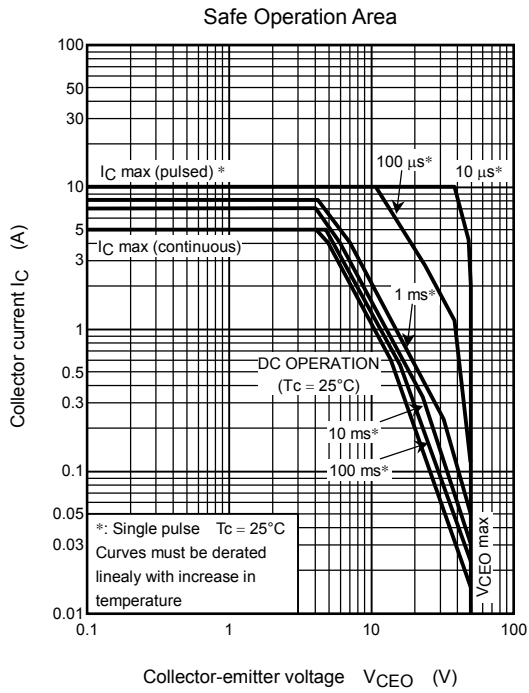
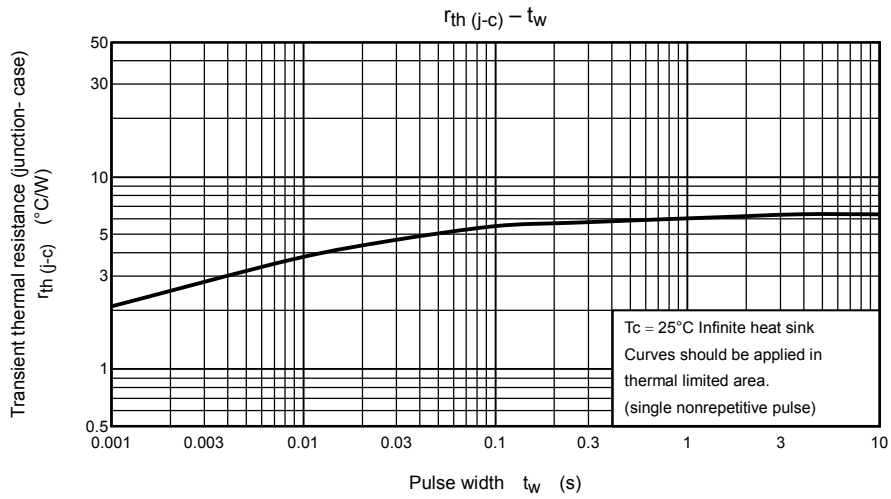
Marking



Explanation of Lot No.







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